Vishay General Semiconductor



TRANSZORB® Transient Voltage Suppressors



PRIMARY CHARACTERISTICS			
V_{WM}	5.0 V to 18 V		
P _{PPM}	1500 W		
P _D	6.5 W		
I _{FSM}	200 A		
T _J max.	175 °C		

DEVICES FOR BI-DIRECTION APPLICATIONS

For bi-directional types, use C suffix (e.g. ICTE-18C). Electrical characteristics apply in both directions.

FEATURES



- Glass passivated chip junction
- · Available in uni-directional and bi-directional
- 1500 W peak pulse power capability with a 10/1000 µs waveform, repetitive rate (duty cycle): 0.01 %
- Excellent clamping capability
- · Very fast response time
- Low incremental surge resistance
- Solder dip 260 °C, 40 seconds
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units for consumer, computer, industrial and telecommunication.

MECHANICAL DATA

Case: Molded epoxy body over passivated junction Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002B and JESD22-B102D

E3 suffix for commercial grade, HE3 suffix for high reliability grade (AEC Q101 qualified)

Polarity: For uni-directional types the color band denotes cathode end, no marking on bi-directional types

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	LIMIT	UNIT		
Peak pulse power dissipation with a 10/1000 μs waveform ⁽¹⁾ (Fig. 1)	P _{PPM}	1500	W		
Peak pulse current with a 10/1000 μs waveform ⁽¹⁾ (Fig. 3)	I _{PPM}	See next table	Α		
Power dissipation on infinite heatsink at T _L = 75 °C (Fig. 8)	P_{D}	6.5	W		
Peak forward surge current 8.3 ms single half sine-wave uni-directional only (2)	I _{FSM}	200	Α		
Maximum instantaneous forward voltage at 100 A for uni-directional only	V_{F}	3.5	V		
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 175	°C		

Notes:

(1) Non-repetitive current pulse, per Fig. 3 and derated above T_A = 25 °C per Fig. 2

(2) 8.3 ms single half sine-wave, duty cycle = 4 pulses per minute maximum

www.vishay.com Document Number: 88356 Revision: 04-Sep-07



ICTE5.0 thru ICTE18C, 1N6373 thru 1N6386

Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS (JEDEC REGISTERED DATA) $(T_A = 25 \text{ °C unless otherwise noted})$							
JEDEC TYPE NUMBER	GENERAL SEMICONDUCTOR PART NUMBER	STAND-OFF VOLTAGE V _{WM} (V)	MINIMUM ⁽³⁾ BREAKDOWN VOLTAGE AT 1.0 mA V _{BR} (V)	MAXIMUM REVERSE LEAKAGE AT V _{WM} I _D (μA)	MAXIMUM CLAMPING VOLTAGE AT I _{PP} = 1.0 A V _C (V)	MAXIMUM CLAMPING VOLTAGE AT I _{PP} = 10 A V _C (V)	MAXIMUM PEAK PULSE CURRENT IPP (A)
UNI-DIRECT	UNI-DIRECTIONAL TYPES						
1N6373 ⁽²⁾	ICTE-5 (2)	5.0	6.0	300	7.1	7.5	160
1N6374	ICTE-8	8.0	9.4	25.0	11.3	11.5	100
1N6375	ICTE-10	10.0	11.7	2.0	13.7	14.1	90
1N6376	ICTE-12	12.0	14.1	2.0	16.1	16.5	70
1N6377	ICTE-15	15.0	17.6	2.0	20.1	20.6	60
1N6378	ICTE-18	18.0	21.2	2.0	24.2	25.2	50
BI-DIRECTIO	BI-DIRECTIONAL TYPES						
1N6382	ICTE-8C	8.0	9.4	50.0	11.4	11.6	100
1N6383	ICTE-10C	10.0	11.7	2.0	14.1	14.5	90
1N6384	ICTE-12C	12.0	14.1	2.0	16.7	17.1	70
1N6385	ICTE-15C	15.0	17.6	2.0	20.8	21.4	60
1N6386	ICTE-18C	18.0	21.2	2.0	24.8	25.5	50

Notes:

- (1) "C" Suffix indicates bi-directional
- (2) ICTE-5 and 1N6373 are not available as bi-directional
- (3) The minimum breakdown voltage as shown takes into consideration the ± 1 V tolerance normally specified for power supply regulation on most integrated circuit manufacturers data sheets. Please consult factory for devices that require reduced clamping voltages where tighter regulated power supply voltages are employed
- (4) Clamping factor: 1.33 at full rated power; 1.20 at 50 % rated power; Clamping factor: the ratio of the actual V_C (Clamping Voltage) to the V_{BR} (Breakdown Voltage) as measured on a specific device

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ICTE-5-E3/54	0.968	54	1400	13" diameter paper tape and reel		
ICTE-5HE3/54 (1)	0.968	54	1400	13" diameter paper tape and reel		

Note:

(1) Automotive grade AEC Q101 qualified

Document Number: 88356
Revision: 04-Sep-07

117

ICTE5.0 thru ICTE18C, 1N6373 thru 1N6386

Vishay General Semiconductor



RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

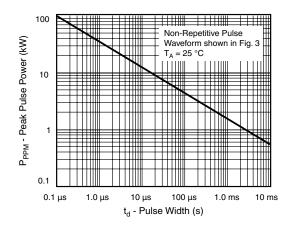


Figure 1. Peak Pulse Power Rating Curve

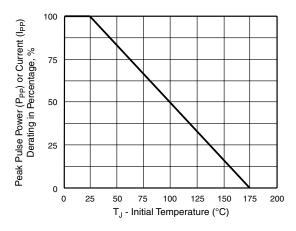


Figure 2. Pulse Power or Current vs. Initial Junction Temperature

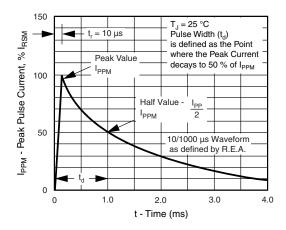


Figure 3. Pulse Waveform

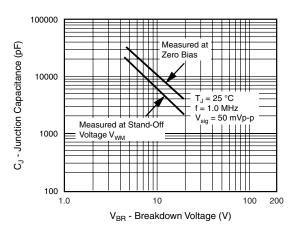


Figure 4. Typical Junction Capacitance Uni-Directional

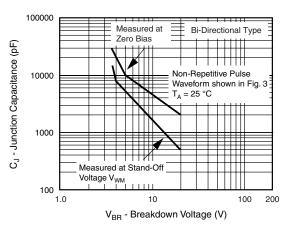


Figure 5. Typical Junction Capacitance

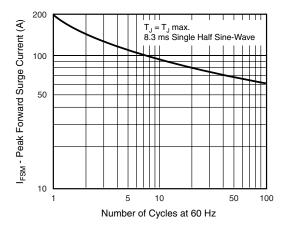


Figure 6. Maximum Non-Repetitive Forward Surge Current Uni-Directional Only

Document Number: 88356 Revision: 04-Sep-07





Vishay General Semiconductor

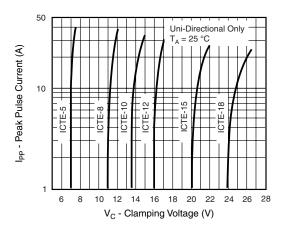


Figure 7. Typical Characteristics Clamping Voltage

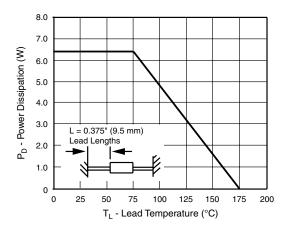
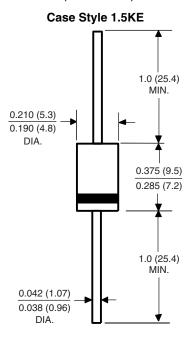


Figure 8. Power Derating Curve

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



Document Number: 88356
Revision: 04-Sep-07

www.vishay.com
119

Legal Disclaimer Notice



Vishay

Notice

Specifications of the products displayed herein are subject to change without notice. Vishay Intertechnology, Inc., or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document. Except as provided in Vishay's terms and conditions of sale for such products, Vishay assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of Vishay products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Vishay for any damages resulting from such improper use or sale.

www.vishay.com Revision: 08-Apr-05